Diode Semiconductor Device - Page 1 of 1



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Inclosur	e Material:
Glass	
Overall I	_ength:
0.345 inc	hes
Termina	I Length:
1.250 inc	hes
Overall [	Diameter:
0.200 inc	hes
Mountin	g Method:
Terminal	
Features	s Provided:
Hermetic	ally sealed case
Semicor	nductor Material:
Silicon	
Voltage	Rating In Volts Per Characteristic:
200.0 re	verse voltage, peak
Current	Rating Per Characteristic:
500.00 m	nilliamperes repetitive peak forward current
Maximu	m Operating Tempurature Per Measurement Point:
200.0 de	grees celsius ambient air
Termina	I Type And Quantity:
2 uninsul	lated wire lead
Shelf Lif	e:
N/a	
Unit Of N	Measure:
Demilita	rization:
No	
Fiig:	
A110a0	